

DUAL OPERATIONAL AMPLIFIER

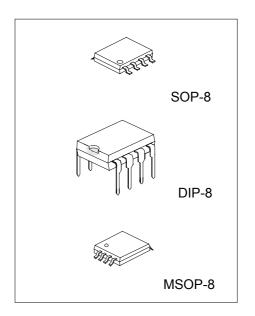
DESCRIPTION

The RC4580 is the dual operational amplifier, specially designed for improving the tone control, which is most suitable for the audio application.

Featuring noiseless, higher gain bandwidth, high output current and low distortion ratio, and it is most suitable not only for acoustic electronic parts of audio pre-amp and active filter, but also for the industrial measurement tools. It is also suitable for the head phone amp at higher output current, and further more, it can be applied for the handy type set operational amplifier of general purpose in application of low voltage single supply type which is properly biased of the input low voltage source.

FEATURES

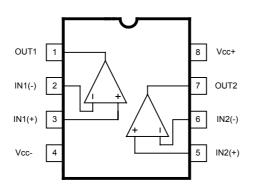
*Operating Voltage $(\pm 2\text{V to} \pm 16\text{V})$ *Low Input Noise Voltage $(0.8~\mu~\text{Vrms typ.})$ *Wide Gain Bandwidth Product (15MHz typ.) *Low Distortion (0.0005%~typ.) *Slew Rate $(5\text{V}/\mu\text{s typ.})$



ORDERING INFORMATION

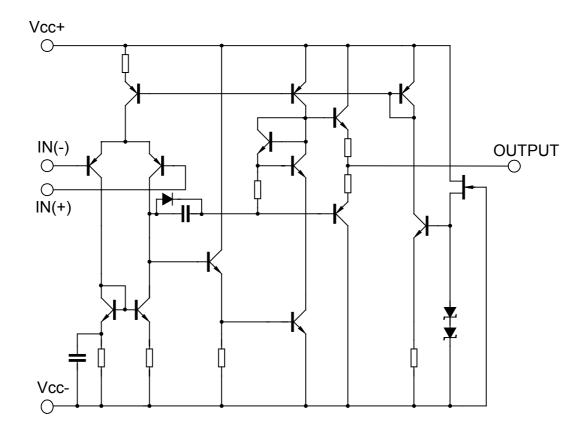
DEVICE	Package Type	MARKING	Packing	Packing Qty
RC4580N	DIP8L	RC4580	TUBE	2000pcs/box
RC4580M/TR	SOP8L	RC4580	REEL	2500pcs/reel
RC4580MM/TR	MSOP8L	RC4580	REEL	3000pcs/reel

PIN CONFIGURATION





TEST CIRCUIT



ABSOLUTE MAXIMUM RATINGS (Ta=25°C)

7 12 0 0 2 0 1 2 1 1 1 1 1 1 1 1 1 1 1 1	100 (10 =0)	-,	
PARAMETER	SYMBOL	RATINGS	UNIT
Supply Voltage	V ⁺ /V ⁻	±16	V
Input Voltage	V _{IC}	±15	V
Differential Input Voltage	V _{ID}	±30	V
Output Current	lo	±50	mA
Power Dissipation	Pb	300 (SOP-8) 800 (DIP-8) 250(TSSOP-8)	mW
Operating Temperature Range	Topr	-40 to+85	°C
Storage Temperature Range	Tstg	-40 to +125	°C

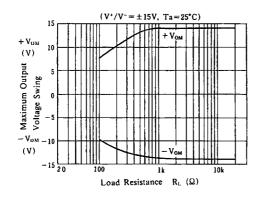


ELECTRICAL CHARACTERISTICS (V ⁺ /V ⁻ =±15V, Ta=25°C)	ELECTRICAL	CHARACTERISTICS	$(V^{+}/V^{-}=+15V. Ta=25^{\circ}C)$
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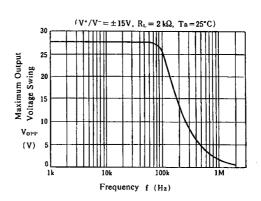
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PARAMETER	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Input Offset Voltage	Vio	R _S ≤10kΩ	-	0.5	3	mV
Input Offset Current	lio		-	5	200	nA
Input Bias Current	lв		ı	100	500	nA
Large Signal Voltage Gain	Av	Vo= \pm 10V, R _L ≥2kΩ	90	110	-	dB
Output Voltage Swing	Vом	$R_L > = 2k\Omega$	±12	±13.5	-	V
Input Common Mode Voltage Range	VICM		±12	±13.5	-	V
Common Mode Rejection Ratio	CMR	R _S ≤10kΩ	80	110	-	dB
Supply Voltage Rejection Ratio	SVR	Rs≤10kΩ	80	110	-	dB
Operating Current	Icc		-	6	9	mA
Slew Rate	SR	R _L ≥2kΩ	-	5	-	V/μs
Gain bandwidth Product	GB	f=10KHz	-	15	-	MHz
Total Harmonic Distortion	THD	Av=20dB,Vo=5V, R_L =2k Ω , f=1KHz	-	0.0005	-	%
Input Noise Voltage	Vni	RIAA Rs=2.2 kΩ,30kHzLPF	-	0.8	-	μVrms

TYPICAL CHARACTERISTICS

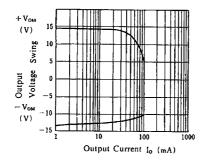
Maximum Output Voltage Swing vs. Load Resistance



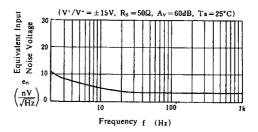
Maximum Output Voltage Swing vs. Frequency



Output Voltage Swing vs. Output Current

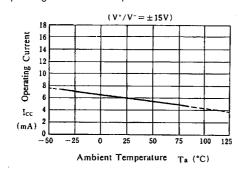


Equivalent Input Noise Voltage vs. Frequency

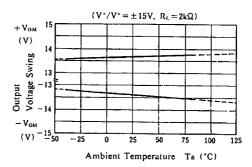




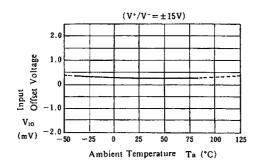
Operating Current vs. Temperature



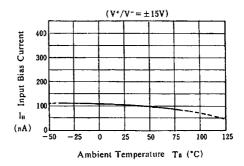
Output Voltage Swing vs. Temperature



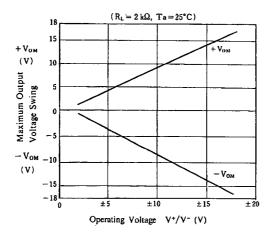
Input Offset Voltage vs. Temperature



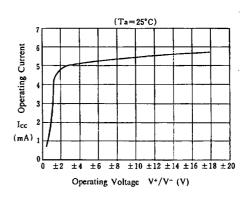
Input Bias Current vs. Temperature



Maximum Output Voltage Swing vs. Operating Voltage



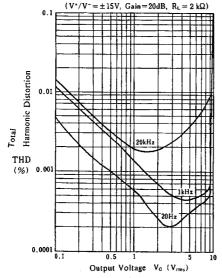
Operating Current vs. Operating Voltage

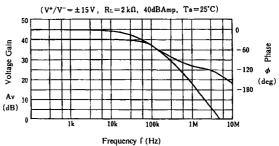




Total Harmonic Distortion vs. Output Voltage

Voltage Gain, Phase vs. Frequency



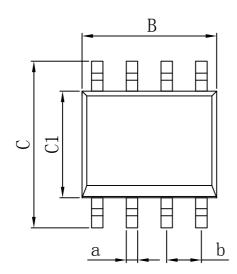


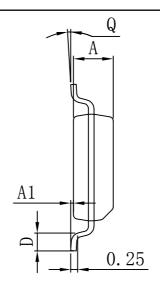
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PACKAGE

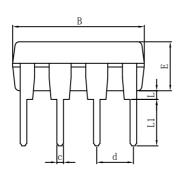
SOP8

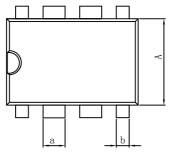




Dimensions In Millimeters							
Symbol :	Min:	Max:	Symbol:	Min:	Max:		
Α	1.225	1.570	D	0.400	0.950		
A1	0.100	0.250	Q	0°	8°		
В	4.800	5.100	а	0.420 TYP			
С	5.800	6.250	b	1.270 TYP			
C1	3.800	4.000					

DIP8



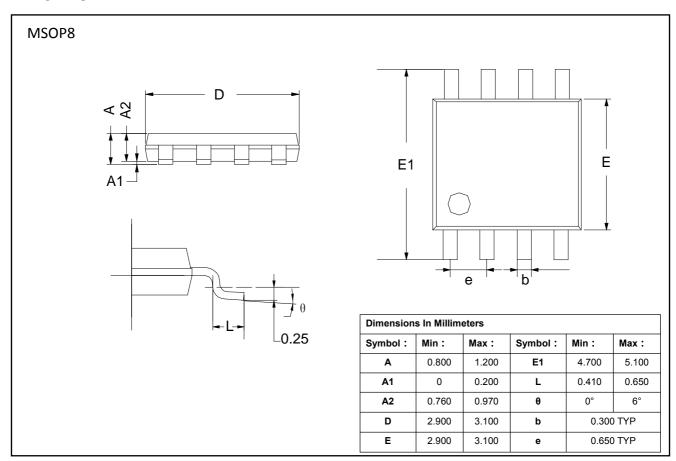




Dimensions In Millimeters							
Symbol :	Min :	Max:	Symbol :	Min :	Max:		
Α	6.100	6.680	L1	3.000	3.600		
В	9.000	9.500	а	1.524 TYP			
D	8.400	9.000	b	0.889 TYP			
D1	7.420	7.820	С	0.457 TYP			
Е	3.100	3.550	d	2.540 TYP			
L	0.500	0.700		•			



PACKAGE



7



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